NSN 5961-00-998-5224

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View Online at https://aerobasegroup.com/nsn/5961-00-998-5224 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.0 emitter to base voltage, static, collector open and 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 7.00 amperes source cutoff current **Power Rating Per Characteristic:** 117.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 70.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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